MILITARY SPECIFICATION

SEMICONDUCTOR DEVICE, TRANSISTOR, PNP, GERMANIUM
TYPES 2N1183, 2N1183A, 2N1183B and
2N1184, 2N1184A, 2N1184B

This Amendment forms a part of Military
Specification MIL-S-19500/1438(EL),
22 June 1966.

Page 1, paragraph 1.4 Table, characteristic $h_{FE}$ column, types 2N1183, A,B data: Replace the Max value "60" with "75".

Page 1, paragraph 1.4 Table, characteristic $f_{c_{rb}}$ column: Replace the Min value "0.5" with "0.35".

Page 5, Table I, Subgroup 2, Item 3076 $h_{FE}$ test data for types 2N1183, A,B: In the Limits Max column, replace "60" with "75".

Page 6, Table I, Subgroup 4, Item 3301 Cutoff Frequency test: In the Limits Min column, replace "0.5" with "0.35".

Custodian:
Army=EL

Preparing activity:
Army=EL

Project No. 5961-A257

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